



50 MHz to 4000 MHz ACTIVE BIAS SILICON GERMANIUM CASCADABLE GAIN BLOCK

Package: SOT-363

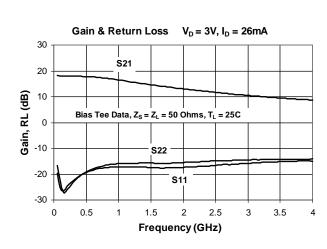




Product Description

RFMD's SGC2363Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with a patented active-bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 3V supply, the SGC2363Z does not require a dropping resistor as compared to typical Darlington amplifiers. The SGC2363Z is designed for high linearity 3V gain block applications that require small size and minimal external components. It is internally matched to $50\,\Omega$.





Features

- Single, Fixed 3V Supply
- No Dropping Resistor Required
- Patented Self-Bias Circuitry
- P_{1dB}=10.1dBm at 1950MHz
- \bullet OIP₃=23dBm at 1950MHz
- Robust 1000V ESD, Class 1C HBM

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS, WCDMA
- IF Amplifier
- Wireless Data, Satellite

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Parameter	Min.	Тур.	Max.	Unit	Condition	
Small Signal Gain	15.5	17.0	18.5	dB	850MHz	
	11.6	13.1	14.6	dB	1950MHz	
		12.3		dB	2400 MHz	
Output Power at 1dB Compression		10.4		dBm	850MHz	
	9.1	10.1		dBm	1950MHz	
		9.6		dBm	2400MHz	
Output Third Order Intercept Point		23.0		dBm	850MHz	
	21.0	23.0		dBm	1950MHz	
		24.0		dBm	2400 MHz	
Input Return Loss	12.0	15.0		dB	1950MHz	
Output Return Loss	10.5	14.5		dB	1950MHz	
Noise Figure		3.7	4.8	dB	1930MHz	
Thermal Resistance		255		°C/W	junction - lead	
Device Operating Voltage		3.0		V		
Device Operating Current	22.0	26.0	30.0	mA		

 $Test\ Conditions:\ V_D=3V,\ I_D=26\ mA\ Typ.,\ OIP_3\ Tone\ Spacing=1\ MHz,\ P_{OUT}\ per\ tone=-5\ dBm,\ T_L=25\ ^\circ C,\ Z_S=Z_L=50\ \Omega$



Absolute Maximum Ratings

•		
Parameter	Rating	Unit
Device Current (I _{CE})	55	mA
Device Voltage (V _{CE})	4	V
RF Input Power* (See Note)	12	dBm
Junction Temp (T _J)	+150	°C
Operating Temp Range (T _L)	-40 to +85	°C
Storage Temp	+150	°C
ESD Rating - Human Body Model (HBM)	Class 1C	
Moisture Sensitivity Level	MSL 1	

^{*}Note: Load condition $Z_L = 50\Omega$.

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions to the device may reduce the device under Absolute Maximum Rating conditions to the device may reduce the device under Absolute Maximum Rating conditions to the device under Absolute Maximum Rating co tions is not implied.

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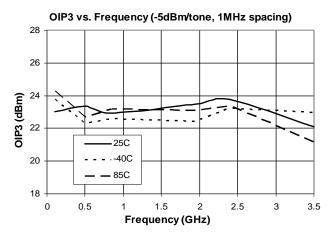
RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in

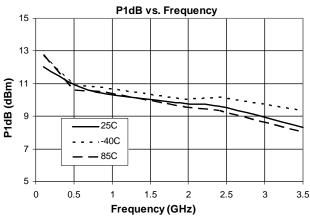
Typical RF Performance with Application Circuit at Key Operating Frequencies

Parameter	Unit	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz	MHz
Small Signal Gain (G)	dB	18.4	18.1	17.0	13.1	12.3	9.8
Output Third Order Intercept Point (OIP ₃)	dBm	23.0	23.5	23.0	23.0	24.0	22.0
Output Power at 1dB Compression (P _{1dB})	dBm	12.1	11.0	10.4	10.1	9.6	8.3
Input Return Loss (IRL)	dB	23.5	19.0	18.0	15.0	16.5	14.0
Output Return Loss (ORL)	dB	22.5	18.5	16.5	14.5	13.0	12.5
Reverse Isolation (S ₁₂)	dB	20.5	21.5	22.0	20.5	20.0	19.0
Noise Figure (NF)	dB	2.9	3.0	3.3	3.7	3.9	4.7

Test Conditions: $V_D = 3V$ $I_D = 26 \text{ mA Typ.}$ OIP_3 Tone Spacing = 1 MHz, P_{OUT} per tone = -5 dBm $T_L = 25 \degree C Z_S = Z_L = 50 \Omega$

Typical Performance with Bias Tee, V_D=3V, I_D=26mA

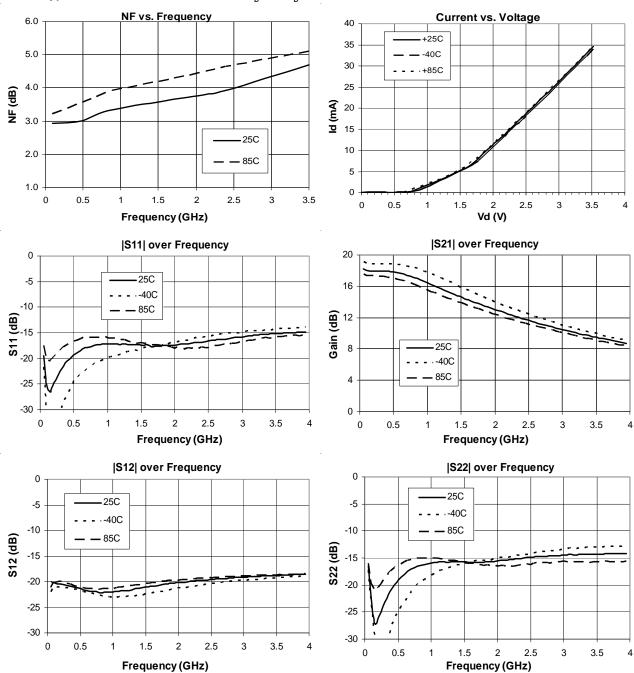




 $I_DV_D < (T_J - T_L)/R_{TH}$, j-I and $T_L = T_{LEAD}$



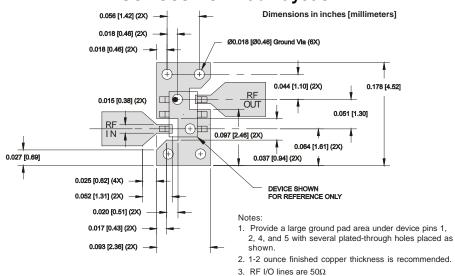
Typical Performance with Bias Tee, $V_D = 3V$, $I_D = 26mA$





Pin	Function	Description
3	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
1, 2, 4, 5	GND	Connection to ground. Use via holes as close to the device ground as possible to reduce ground inductance and achieve optimum RF performance.
6	RF OUT/DC BIAS	RF output and bias pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.

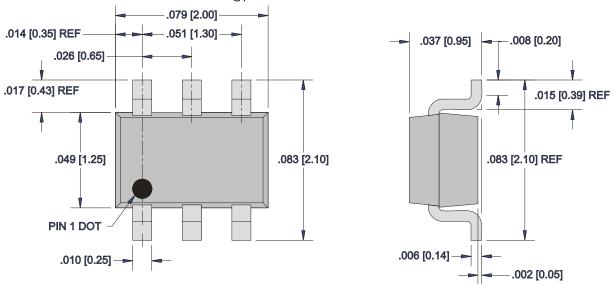
SOT-363 PCB Pad Layout



Package Drawing

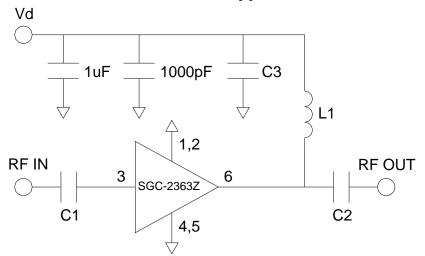
Dimensions in inches (millimeters)

Refer to drawing posted at www.rfmd.com for tolerances.



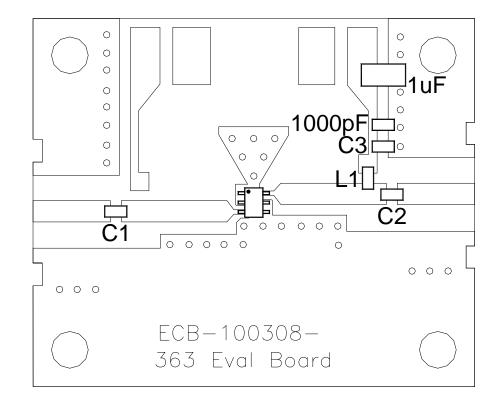


Application Schematic



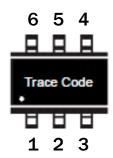
Application Circuit Element Values				
Reference Designator	100-2000MHz	2000-4000MHz		
C1	1000pF	2.7pF		
C2	100pF	6.8pF		
C3	100pF	6.8pF		
L1	150nH	39nH		

Evaluation Board Layout





Part Identification



Ordering Information

Ordering Code	Description
SGC2363Z	7" Reel with 3000 pieces
SGC2363ZSQ	Sample Bag with 25 pieces
SGC2363ZSR	7" Reel with 100 pieces
SGC2363ZPCK1	100 MHz to 2000 MHz PCBA with 5-piece sample bag
SGC2363ZPCK2	2000 MHz to 4000 MHz PCBA with 5-piece sample bag